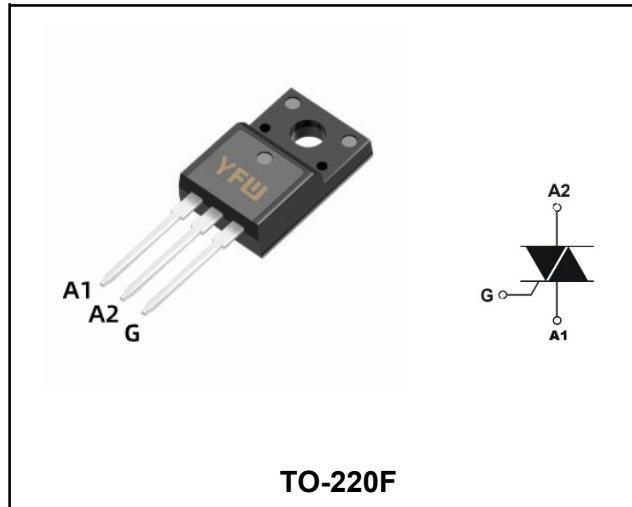


4A 3Quadrants TRIACs
Product Summary

| Symbol | Value | Unit |
|-------------------|---------|------|
| $I_{T(RMS)}$ | 4 | A |
| $V_{DRM} V_{RRM}$ | 600/800 | V |
| V_{TM} | 1.55 | V |

Features

With high ability to withstand the shock loading of large current, With high commutation performances, 3 quadrants products especially recommended for use on inductive load.


TO-220F
Application

Washing machine, vacuums, massager, solid state relay, AC Motor speed regulation and so on.

Absolute maximum ratings (Ta=25°C unless otherwise noted)

| Parameter | Symbol | Value | | Unit |
|---|--------------|--------------|----|-----------|
| Repetitive peak off-state voltage | V_{DRM} | 600/800 | | V |
| Repetitive peak reverse voltage | V_{RRM} | 600/800 | | V |
| RMS on-state current | $I_{T(RMS)}$ | 4 | | A |
| Non repetitive surge peak on-state current (full cycle, F=50Hz) | I_{TSM} | 40 | | A |
| I^2t value for fusing ($t_p=10ms$) | I^2t | 8 | | A^2s |
| Critical rate of rise of on-state current ($ I_G = 2 \times I_{GT} $) | dI/dt | I - II - III | 50 | $A/\mu s$ |
| Peak gate current | I_{GM} | 4 | | A |
| Average gate power dissipation | $P_G (AV)$ | 1 | | W |
| Junction Temperature | T_J | -40~+125 | | °C |
| Storage Temperature | T_{STG} | -40 ~+150 | | °C |

Electrical characteristics ($T_A=25^\circ C$, unless otherwise noted)

| Parameter | Symbol | Test Condition | | Value | | | Unit |
|--|-----------|---|----------|------------|-----------|------------|------------|
| | | | | TW | SW | CW | |
| Gate trigger current | I_{GT} | $V_D=12V$ $R_L=33\Omega$ $T_j=25^\circ C$ | I-II-III | ≤ 5 | ≤ 10 | ≤ 35 | mA |
| Gate trigger voltage | V_{GT} | | I-II-III | ≤ 1.3 | | | |
| Gate non-trigger voltage | V_{GD} | $V_D=V_{DRM}$ $T_j=125^\circ C$ | | ≥ 0.2 | | | V |
| latching current | I_L | $I_G=1.2I_{GT}$ | I-III-IV | ≤ 10 | ≤ 25 | ≤ 50 | mA |
| | | | II | ≤ 15 | ≤ 30 | ≤ 60 | |
| Holding current | I_H | $I_T = 100mA$ | | ≤ 10 | ≤ 15 | ≤ 35 | mA |
| Critical-rate of rise of commutation voltage | dV_D/dt | $V_D=67\%_{DRM}$ Gate Open $T_j=125^\circ C$ | | ≥ 20 | ≥ 40 | ≥ 400 | V/ μ s |

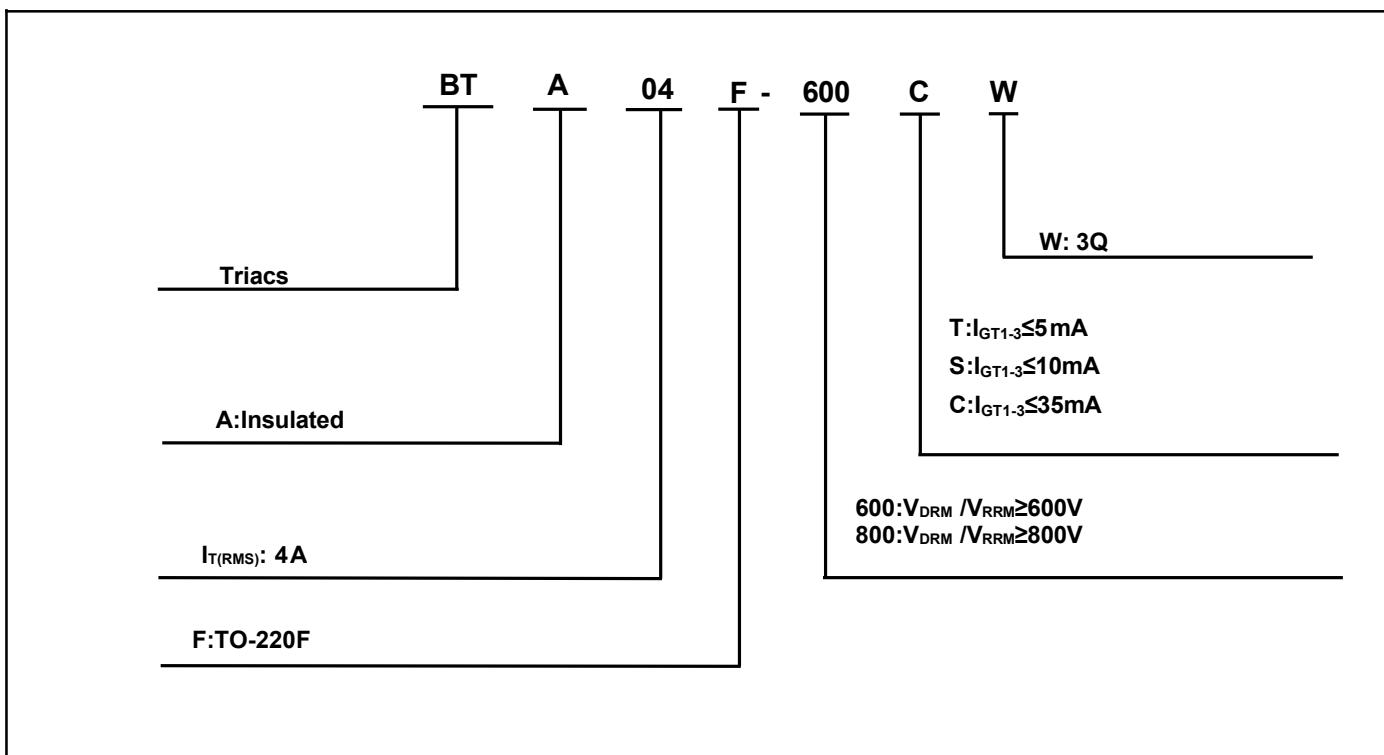
STATIC CHARACTERISTICS

| | | | | | | | |
|-----------------------------------|-----------|-----------------------------|-------------------|------------|------------|------------|---------|
| Forward "on" voltage | V_{TM} | $I_{TM}=6A$ $t_p=380\mu s$ | ≤ 1.55 | | | V | |
| Repetitive Peak Off-State Current | I_{DRM} | $V_D=V_{DRM}$ $V_R=V_{RRM}$ | $T_j=25^\circ C$ | ≤ 5 | ≤ 5 | ≤ 5 | μA |
| Repetitive Peak Reverse Current | I_{RRM} | | $T_j=125^\circ C$ | ≤ 0.5 | ≤ 0.5 | ≤ 0.5 | mA |

THERMAL RESISTANCES

| | | | | | | |
|--------------------|---------------|----------------------|-----|--|--|--------------|
| Thermal resistance | $R_{th(j-c)}$ | Junction to case(AC) | 3.3 | | | $^\circ C/W$ |
| | $R_{th(j-a)}$ | Junction to ambient | 60 | | | $^\circ C/W$ |

Ordering Information



Typical Characteristics

FIG.1: Maximum power dissipation versus RMS on-state current (full cycle)

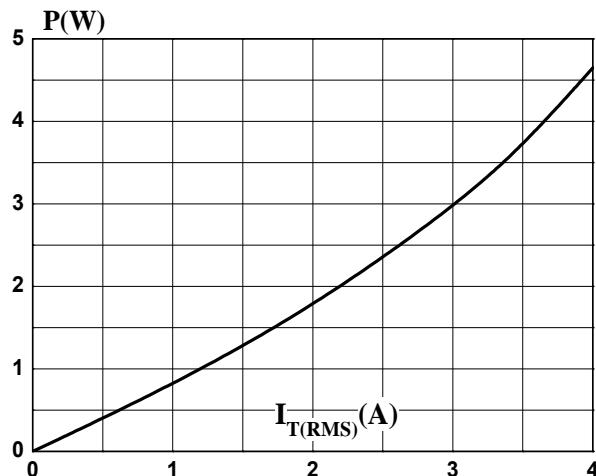


FIG.3: Surge peak on-state current versus number of cycles

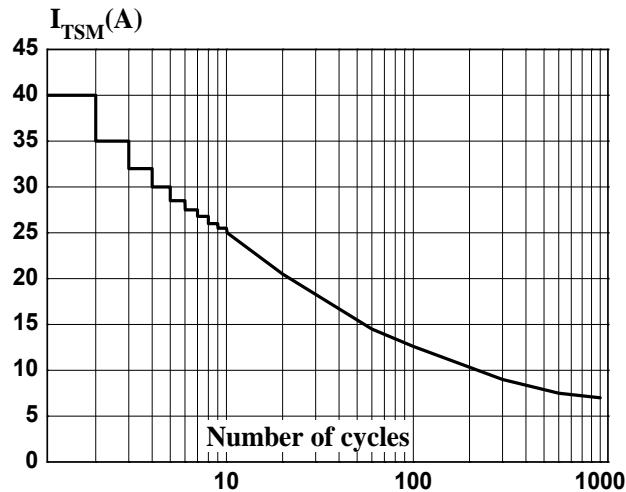


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10\text{ms}$

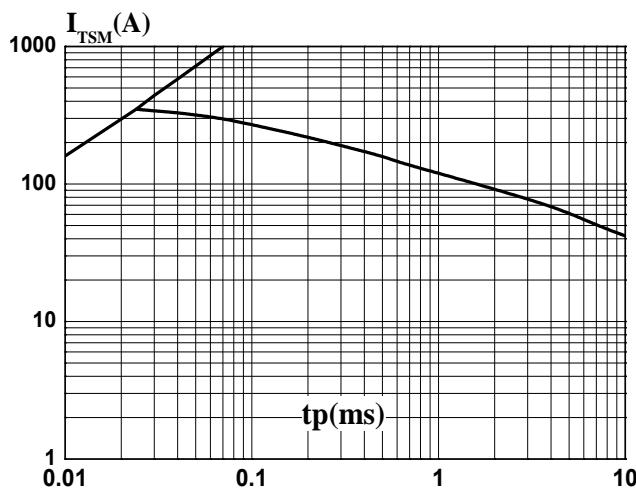


FIG.2: RMS on-state current versus case temperature (full cycle)

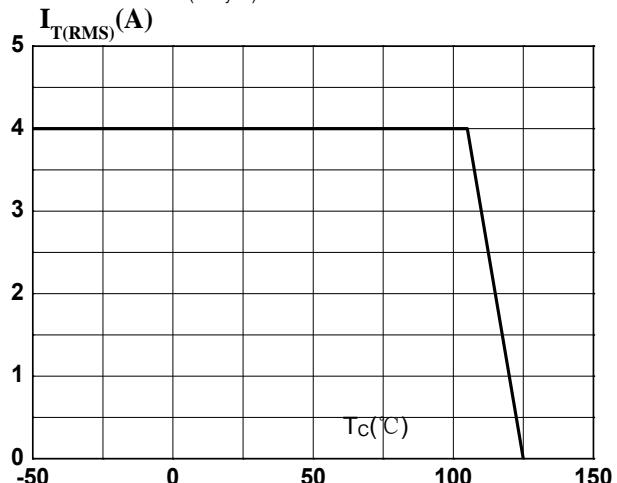


FIG.4: On-state characteristics (maximum values)

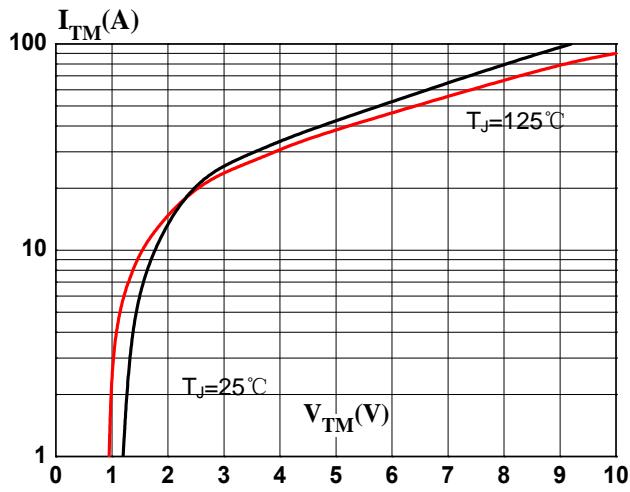
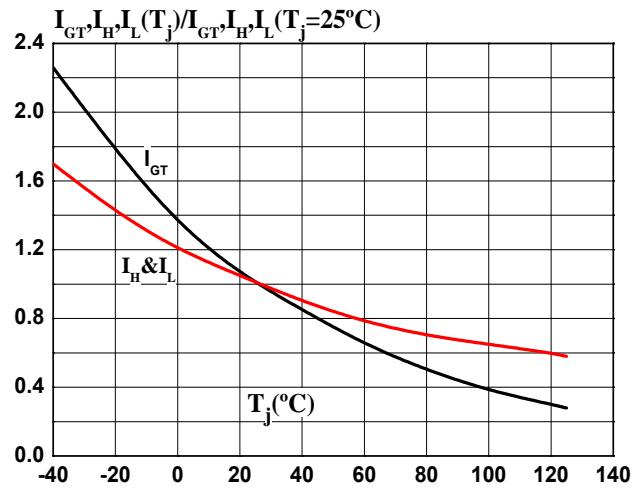
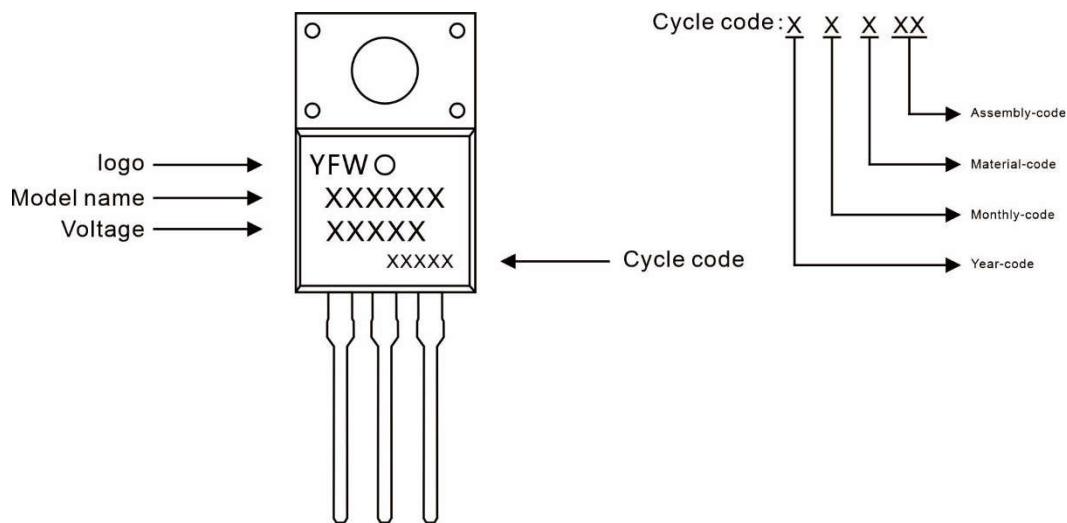


FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature (typical values)



Marking Diagram

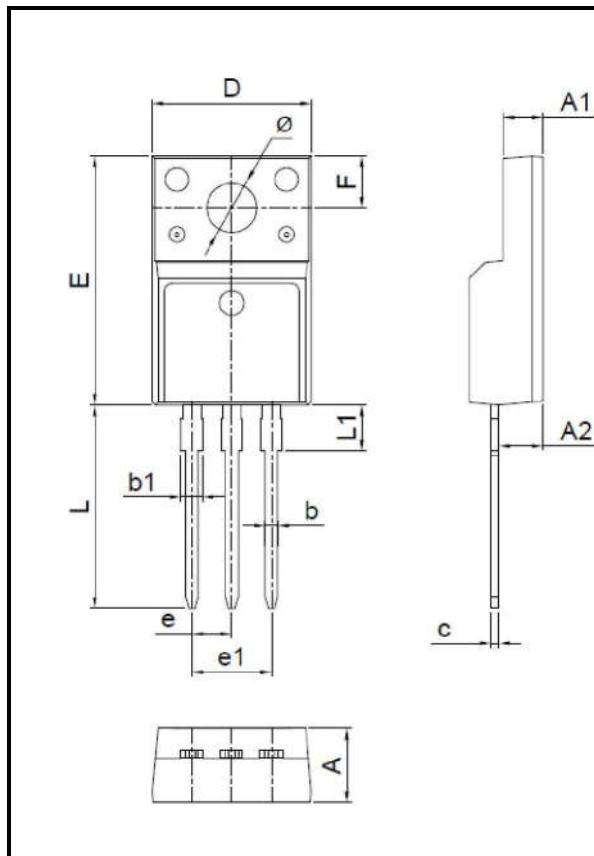


Ordering information

| Model name | Package | Unit Weight | Base Quantity | Packing Quantity |
|---------------|---------|---------------|---------------|----------------------------|
| BTA04F | TO-220F | 0.06oz(1.74g) | 50pcs/tube | 1000PCS/Box 5000PCS/Carton |

Package Dimensions

TO-220F



Technical drawing of the TO-220F package showing front and side views with dimension labels A through F and A1 through A2.

| Symbol | Millimeter | | Inches | |
|--------|------------|-------|--------|-------|
| | Min. | Max. | Min. | Max. |
| A | 4.50 | 4.90 | 0.177 | 0.193 |
| A1 | 2.34 | 2.74 | 0.092 | 0.108 |
| A2 | 2.66 | 2.86 | 0.105 | 0.113 |
| b | 0.75 | 0.85 | 0.030 | 0.033 |
| b1 | 1.24 | 1.44 | 0.049 | 0.057 |
| c | 0.40 | 0.60 | 0.016 | 0.024 |
| D | 10.00 | 10.32 | 0.394 | 0.406 |
| E | 15.75 | 16.05 | 0.620 | 0.632 |
| e | 2.44 | 2.64 | 0.096 | 0.104 |
| e1 | 4.88 | 5.28 | 0.192 | 0.208 |
| F | 3.10 | 3.5 | 0.122 | 0.138 |
| L | 13.50 | 13.90 | 0.531 | 0.547 |
| L1 | 2.90 | 3.30 | 0.114 | 0.130 |
| Φ | 3.10 | 3.30 | 0.122 | 0.130 |

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